MOSFETs Silicon N-Channel MOS (U-MOSVI-H)

# TK50P03M1

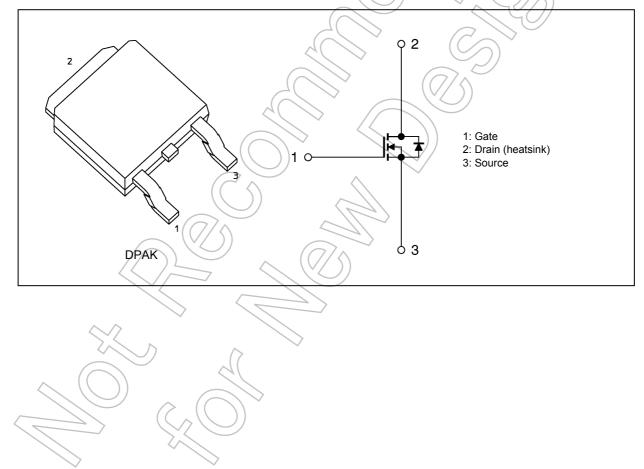
### 1. Applications

- Switching Voltage Regulators
- Motor Drivers
- Power Management Switches

#### 2. Features

- (1) High-speed switching
- (2) Low gate charge:  $Q_{SW} = 8.2 \text{ nC}$  (typ.)
- (3) Low drain-source on-resistance:  $R_{DS(ON)} = 5.8 \text{ m}\Omega$  (typ.) ( $V_{GS} = 10 \text{ V}$ )
- (4) Low leakage current:  $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 30 \ V)$
- (5) Enhancement mode:  $V_{th} = 1.3$  to 2.3 V ( $V_{DS} = 10$  V,  $I_D = 0.2$  mA)

### 3. Packaging and Internal Circuit



### 4. Absolute Maximum Ratings (Note) ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V <sub>DSS</sub>	30	V
Gate-source voltage			V <sub>GSS</sub>	±20	
Drain current (DC)		(Note 1)	I <sub>D</sub>	50	А
Drain current (pulsed)		(Note 1)	I <sub>DP</sub>	150	
Power dissipation	(T <sub>c</sub> = 25°C)		PD	47	W
Single-pulse avalanche energy		(Note 2)	E <sub>AS</sub>	65	mJ
Single-pulse avalanche current			I <sub>AS</sub>	50	А
Channel temperature		4	T <sub>ch</sub>	150	°C
Storage temperature			T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### 5. Thermal Characteristics

	Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	$\langle \langle \rangle$	R <sub>th(ch-c)</sub>	2.65	°C/W
Channel-to-ambient thermal resistance	$\langle \rangle$	R <sub>th(ch-a)</sub>	125	

Note 1: Ensure that the channel temperature does not exceed 150°C. Note 2:  $V_{DD}$  = 24 V,  $T_{ch}$  = 25°C (initial), L = 20 µH,  $R_G$  = 25  $\Omega$ ,  $I_{AS}$  = 50 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

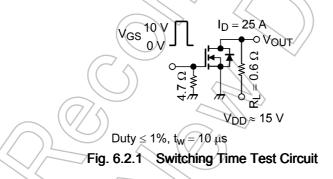
### 6. Electrical Characteristics

### 6.1. Static Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±20 V, $V_{DS}$ = 0 V			±0.1	μA
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V	$\langle$		10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	30		—	V
	V <sub>(BR)DSX</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = -20 V	15	$\langle \gamma \rangle$	_	
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.2 mA	1.3	2_	2.3	
Drain-source on-resistance	R <sub>DS(ON)</sub>	$V_{GS} = 4.5 V, I_D = 25 A$	$V \uparrow$	7.5	9.8	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 25 A	9	5.8	7.5	

## 6.2. Dynamic Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	- [	21700	_	pF
Reverse transfer capacitance	C <sub>rss</sub>		_((	125	_	
Output capacitance	C <sub>oss</sub>		R	380	) —	
Gate resistance	r <sub>g</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 5 MHz	$\sim -$	1.2	3.3	Ω
Switching time (rise time)	tr	See Figure 6.2.1.		20	_	ns
Switching time (turn-on time)	t <sub>on</sub>		~_]	25	_	
Switching time (fall time)	t <sub>f</sub>			22		
Switching time (turn-off time)	t <sub>off</sub>		<u> </u>	64	_	



## 6.3. Gate Charge Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

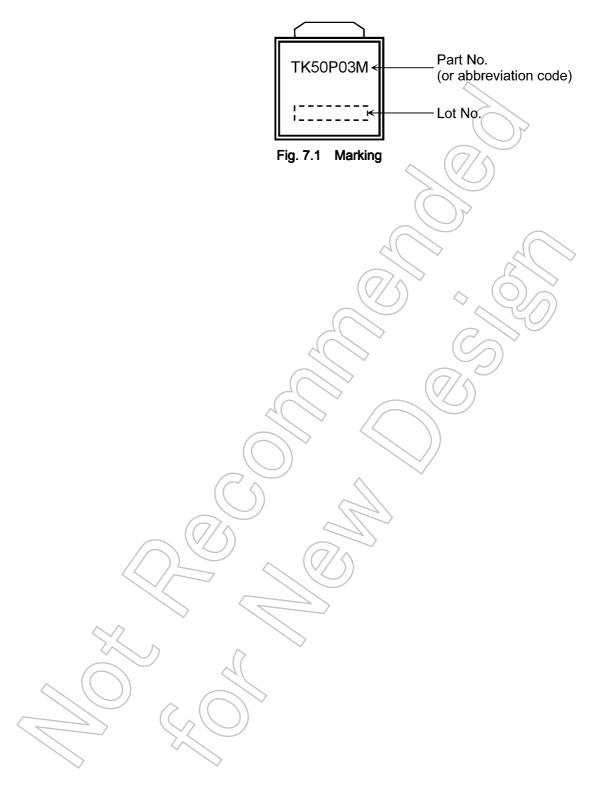
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus		$V_{DD}\approx 24$ V, $V_{GS}$ = 10 V, $I_{D}$ = 50 A		25.3	_	nC
gate-drain)		$V_{DD}\approx 24~V,~V_{GS}$ = 5 V, I <sub>D</sub> = 50 A		13.3		
Gate-source charge 1	Q <sub>gs1</sub>	$V_{DD}\approx 24~V,~V_{GS}\text{ = }10~V,~I_{D}\text{ = }50~A$		6.3	_	
Gate-drain charge	Q <sub>gd</sub>			4.6	_	
Gate switch charge	Q <sub>SW</sub>			8.2		

## 6.4. Source-Drain Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

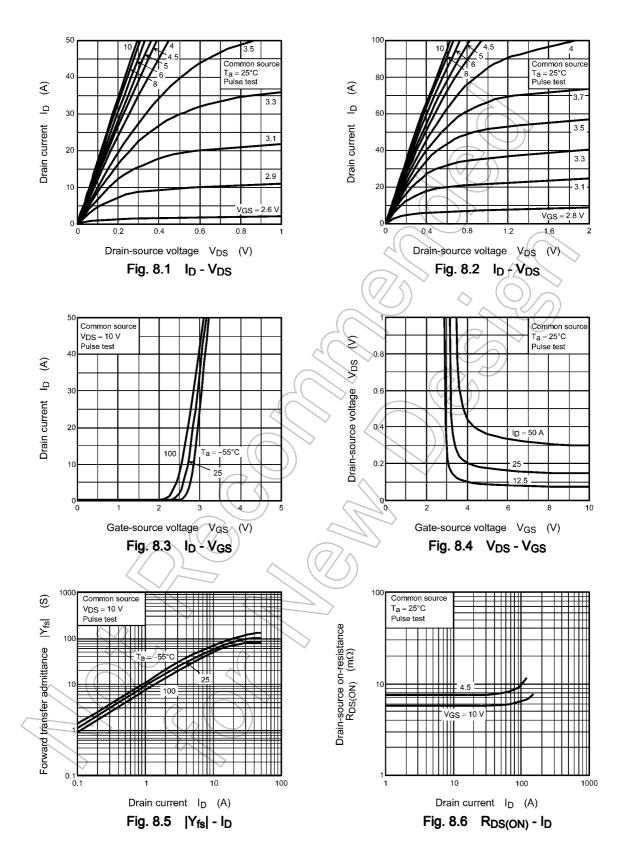
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (	Note 3)	I <sub>DRP</sub>	—	_	_	150	А
Diode forward voltage		V <sub>DSF</sub>	I <sub>DR</sub> = 50 A, V <sub>GS</sub> = 0 V	_	_	-1.2	V

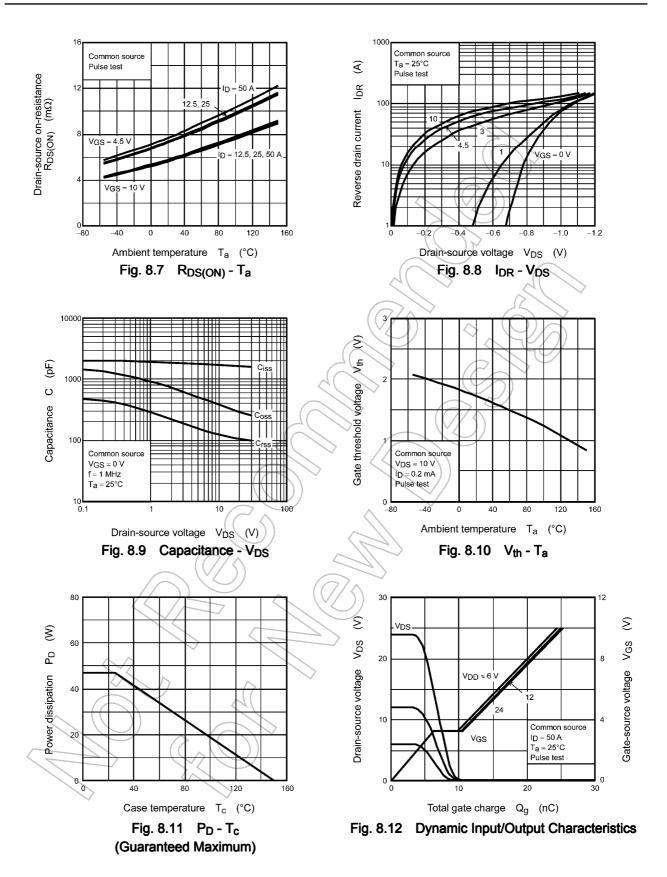
Note 3: Ensure that the channel temperature does not exceed 150°C.

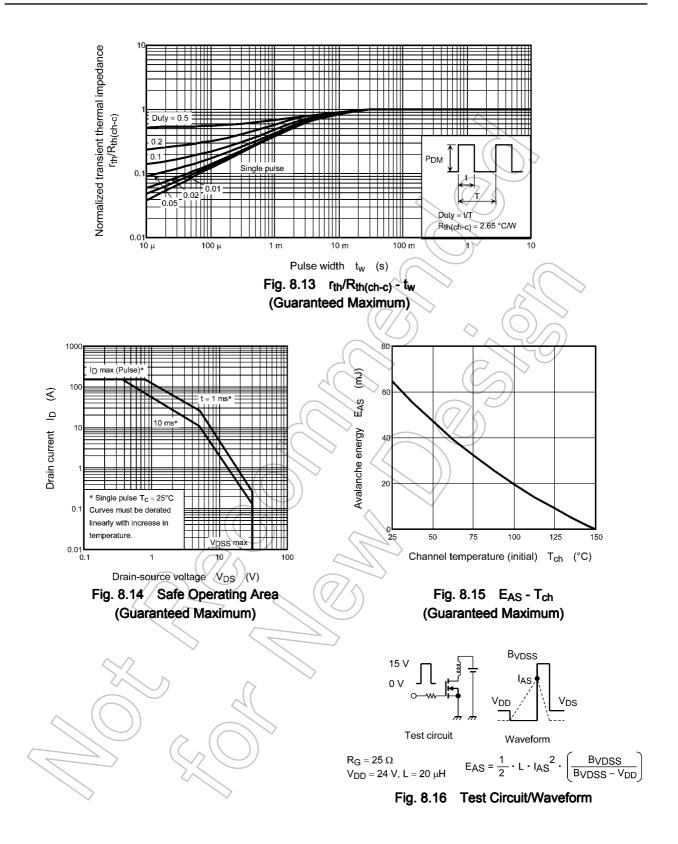
7. Marking



### 8. Characteristics Curves (Note)





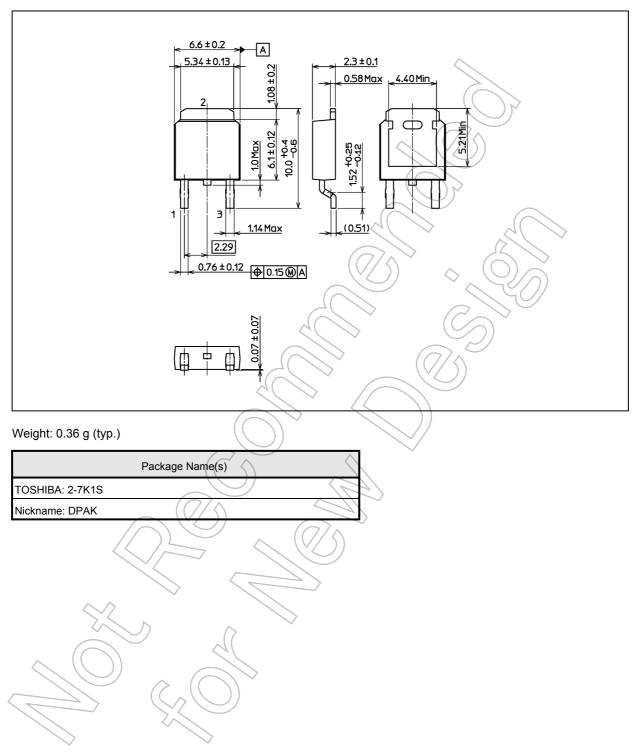


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

## TK50P03M1

### **Package Dimensions**

Unit: mm



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